CONTENTS

| Aleksandrov P. A., Baranova E. K., Baranova I. V., Budaragin V. V., Litvinov V. L., Svechnikov A. B. <i>Dij</i> |
|---|
| ferences between the Effect of Radiation on Nanoelectronic Materials, Devices and Circuits, and on their Mi |
| The work provides a systematic analysis of the effects which should be taken into account in investigation of radiation effects in nanoelectronic materials/devices. The physical differences of the influence of radiation these objects as compared with their microelectronic analogues are considered. The analysis is supported by theoretical and experimental results published in the literature, as well as estimates. Some practical recommendations are given and tasks that require special study are formulated. Keywords: nanoelectronics, radiation damage, electronic materials |
| Yashin K. D., Terpinskaya T. I., Osipovich V. S., Lemesh R. G., Gavnerko G. K., Zilberman R. D., Petro |
| wich V. S. Technology of Creation Medical Nanobioinformation Diagnostic System on Semiconductor Nanocrystals |
| Rathkeen L. S. Nanotechnological Schools of Russia: Stages of Development & International Cooperation . 1 October 5—7, 2011 at Academician physical-technological university — scientific & educational centre of nanotechnologies of Russian academy of sciences (Sankt-Petersburg) under the Chairmanship of the President of Russian nanotechnological society (RNS) Victor A. Bykov, Doctor of Science (Tech.), was organize scientific & practical conference of RNS "Russian nanotechnologies on world market: experience of success & cooperation, problems & prospective", on which were presented reports by different directions of brunc development in Russia. Keywords: Russian academy of sciences (RAS), Russian nanotechnological society (RNS), nanomaterials nanotechnologies, nanoeducation, nanoindustry, surface-active meanings (SAM), nanotubes, nanoparticles nanocomposites |
| Belozubov E. M., Belozubova N. E., Vasil'ev V. A. Increasing to Stability of Thin-Film Nano- and Microelectromechanical Systems of Pressure Sensors for Systems of Checking Measuring and Diagnostics of Technicals Complex Objects |
| Soloviev A. N., Alexeev V. E. Gyro-Free Inertial Navigation System Based on Distributed Set of Acceler rometers |

| Afonin S. M. Characteristics of Composite Piezoactuators for Nano- and Micrometric Movement for Parallel and |
|---|
| Coded Control 32 |
| Mechanical and regulational characteristics for simple and composite a piezoactuators for parallel and coded |
| control are proposed. Transfer functions of a piezomotors for parallel and coded control are obtained. |
| Keywords: mechanical and regulational characteristics, simple and composit a piezoactuator, parallel and |
| coded control, transfer functions |
| |

Keywords: microsystem technics, bending rigidity of an executive element, deformation, measuring dynamic indentation, dependence "loading-deformation"

Maltsev P. P., Matveenko O. S., Gnatyuk D. L., Lisitskiy A. P., Fedorov Yu. V., Bunegina S. L., Krapuchin D. V. Review of Implementation of Planar X-Band Antennas with Two Metallization Layers . . 45 Development results of flat antennas with double-sided metallization for ultra wide band systems are examined. Realization of flat dipoles and Uda—Yagi antennas is analyzed. It is demonstrated that the most effective way to reduce antenna size is optimization of topology of patch and ground conductor.

Keywords: UWB antenna, X-band, planar antenna, monopole, coplanar, Uda—Yagi antenna, fractal, metamaterial

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